

## Features

- Frequency Range: 20~500MHz
- Active Bias Design Supply Temperature Compensation
- Standard Hermetic Package
- Operating Temperature Range: -55°C ~ +85°C

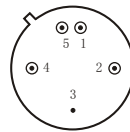
## Specifications (50 Ω, V<sub>CC</sub> = +12V, T<sub>A</sub> = -55°C ~ +85°C)

Parameter	Symbol	Unit	Guaranteed	Typical
Frequency Range	f <sub>L</sub> ~f <sub>H</sub>	MHz	100~500	20~500
Gain	G <sub>p</sub>	dB	≥17.0	18.5
Gain Flatness	ΔG <sub>p</sub>	dB	≤±1.0	±0.5
Noise Figure	F <sub>n</sub>	dB	≤5.0 Δ	4.0
VSWR	VSWR	--	≤2.5:1	1.8:1
VGC Range	Att	dB	≥30.0	--
Output Power @ 1dB Compression	P <sub>-1</sub>	dBm	≥1.0 * Δ	5.0
DC Current	I <sub>CC</sub>	mA	--	35
Turning Voltage	V <sub>t</sub>	V	--	0~12/0~5

- 1) "\*"f = 200MHz; "Δ" T<sub>A</sub> = 24 ± 1°C;
- 2) G<sub>p</sub> and F<sub>n</sub> are tested at V<sub>t</sub> = 12VDC.

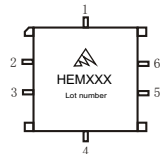
## Maximum Rating

DC Voltage : +15VDC  
RF Input: +10dBm  
Storage Temp: +125°C



TO-8G

1. V<sub>t</sub>
2. RFin
3. GND
4. RFout
5. V<sub>CC</sub>

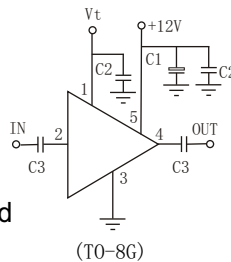


SMO-8E

1. RFin
2. N.C
3. N.C
4. RFout
5. V<sub>CC</sub>
6. V<sub>t</sub>

## Application Notes

1. Typical application shown as right, C<sub>1</sub> = 3.3~22 μF; C<sub>2</sub> = 3300~6800 pF; C<sub>3</sub> = 3300 pF
2. Anti-electrostatic measures should be adopted.
3. See assembly section for mounting method
4. Connectorized package (SMA-4)



(TO-8G)

## Typical Curve

